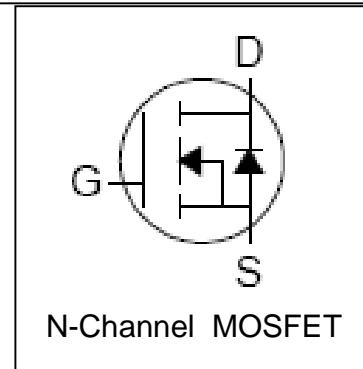
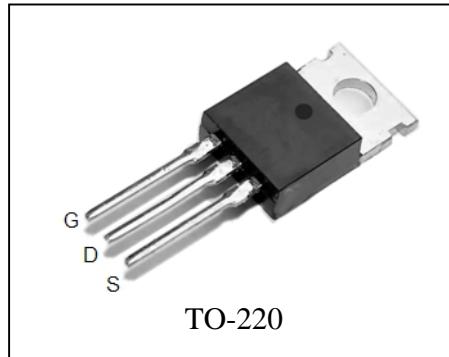


Features

- 40V/120A,
 $R_{DS(ON)} = 3.5\text{m}\Omega$ (Typ.) @ $V_{GS} = 10\text{V}$
- Super High Dense Cell Design
- Ultra Low On-Resistance
- 100% avalanche tested
- Lead Free and Green Devices Available
(RoHS Compliant)

Pin Description



Applications

- DC-DC Converters
- Power Supply

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
Common Ratings ($T_A = 25^\circ\text{C}$ Unless Otherwise Noted)			
V_{DSS}	Drain-Source Voltage	40	V
V_{GSS}	Gate-Source Voltage	± 20	
T_J	Maximum Junction Temperature	175	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-55 to 175	$^\circ\text{C}$
I_S	Diode Continuous Forward Current $T_c = 25^\circ\text{C}$	120 ^①	A
Mounted on Large Heat Sink			
I_{DP}	300 μs Pulse Drain Current Tested	$T_c = 25^\circ\text{C}$	480 ^②
I_D	Continuous Drain Current ($V_{GS} = 10\text{V}$)	$T_c = 25^\circ\text{C}$	120 ^①
		$T_c = 100^\circ\text{C}$	103
P_D	Maximum Power Dissipation	$T_c = 25^\circ\text{C}$	150
		$T_c = 100^\circ\text{C}$	75
$R_{\theta JC}$	Thermal Resistance-Junction to Case	1.0	$^\circ\text{C}/\text{W}$
Drain-Source Avalanche Ratings			
$E_{AS}^{③}$	Avalanche Energy, Single Pulsed	400	mJ

Electrical Characteristics ($T_A=25^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Condition	RU40120R			Unit
			Min.	Typ.	Max.	
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}, I_{\text{DS}}=250\mu\text{A}$	40			V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{\text{DS}}=40\text{V}, V_{\text{GS}}=0\text{V}$ $T_J=85^\circ\text{C}$			1	μA
					10	
$V_{\text{GS(th)}}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{DS}}=250\mu\text{A}$	2	3	4	V
I_{GSS}	Gate Leakage Current	$V_{\text{GS}}=\pm 20\text{V}, V_{\text{DS}}=0\text{V}$			± 100	nA
$R_{\text{DS(ON)}}$ ^④	Drain-Source On-state Resistance	$V_{\text{GS}}=10\text{V}, I_{\text{DS}}=60\text{A}$		3.5	4.5	mΩ
Diode Characteristics						
V_{SD} ^④	Diode Forward Voltage	$I_{\text{SD}}=60\text{A}, V_{\text{GS}}=0\text{V}$		0.8	1.2	V
t_{rr}	Reverse Recovery Time	$I_{\text{SD}}=60\text{A}, dI_{\text{SD}}/dt=100\text{A}/\mu\text{s}$		33		ns
Q_{rr}	Reverse Recovery Charge			30		nC
Dynamic Characteristics ^⑤						
R_{G}	Gate Resistance	$V_{\text{GS}}=0\text{V}, V_{\text{DS}}=0\text{V}, F=1\text{MHz}$		1.8		Ω
C_{iss}	Input Capacitance	$V_{\text{GS}}=0\text{V},$ $V_{\text{DS}}=20\text{V},$ Frequency=1.0MHz		3700		pF
C_{oss}	Output Capacitance			680		
C_{rss}	Reverse Transfer Capacitance			345		
$t_{\text{d(ON)}}$	Turn-on Delay Time	$V_{\text{DD}}=20\text{V}, R_{\text{L}}=30\Omega,$ $I_{\text{DS}}=60\text{A}, V_{\text{GEN}}=10\text{V},$ $R_{\text{G}}=4.7\Omega$		36		ns
t_{r}	Turn-on Rise Time			205		
$t_{\text{d(OFF)}}$	Turn-off Delay Time			85		
t_{f}	Turn-off Fall Time			45		
Gate Charge Characteristics ^⑤						
Q_{g}	Total Gate Charge	$V_{\text{DS}}=32\text{V}, V_{\text{GS}}=10\text{V},$ $I_{\text{DS}}=60\text{A}$		90		nC
Q_{gs}	Gate-Source Charge			32		
Q_{gd}	Gate-Drain Charge			37		

Notes: ①Calculated continuous current based on maximum allowable junction temperature. Limited by bonding wire.

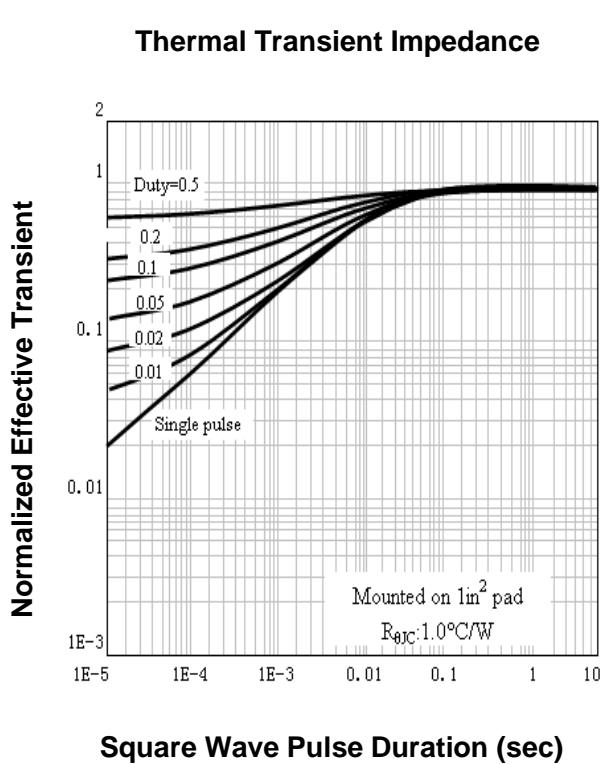
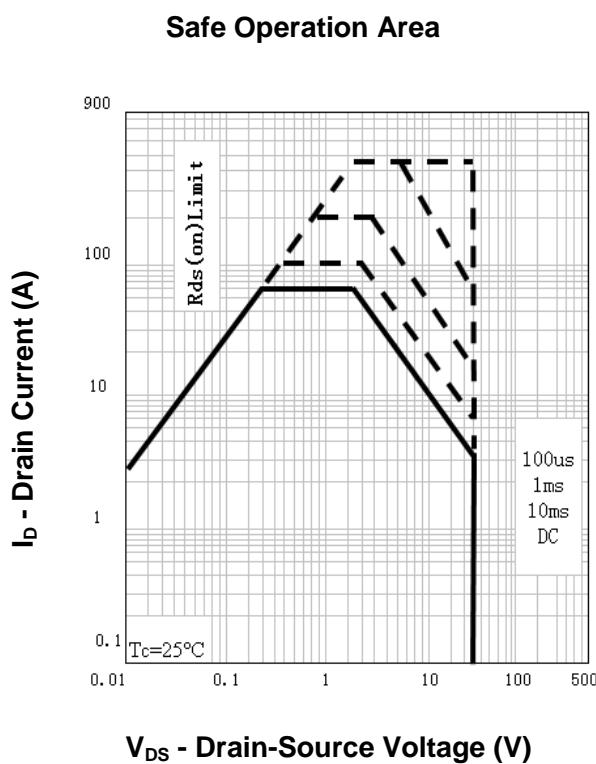
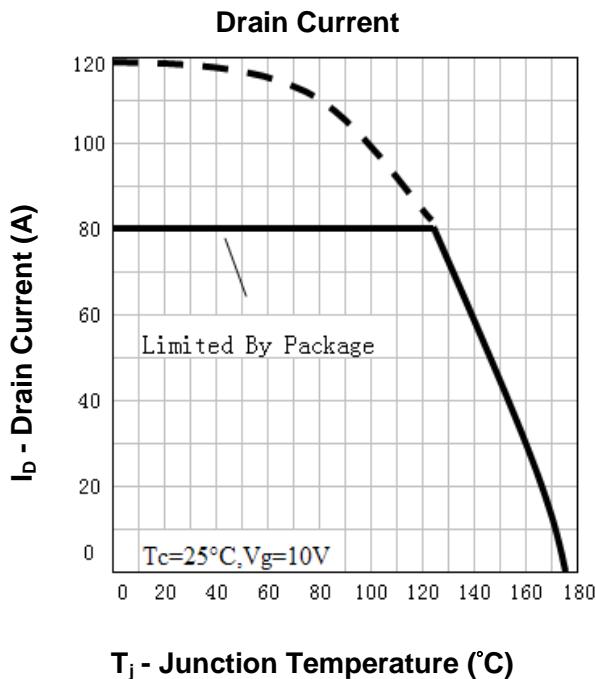
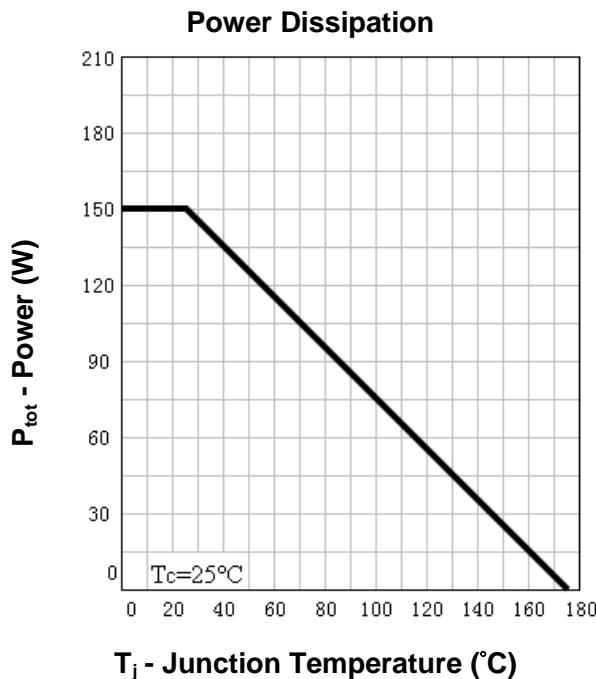
②Pulse width limited by safe operating area..

③Limited by $T_{J\text{max}}$, $I_{AS}=40\text{A}$, $V_{DD}=32\text{V}$, $R_G=47\Omega$, Starting $T_J=25^\circ\text{C}$.

④Pulse test ; Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

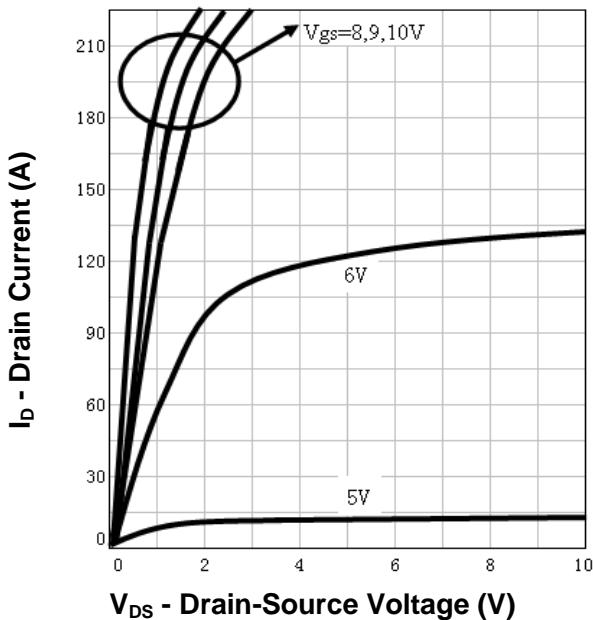
⑤Guaranteed by design, not subject to production testing.

Typical Characteristics

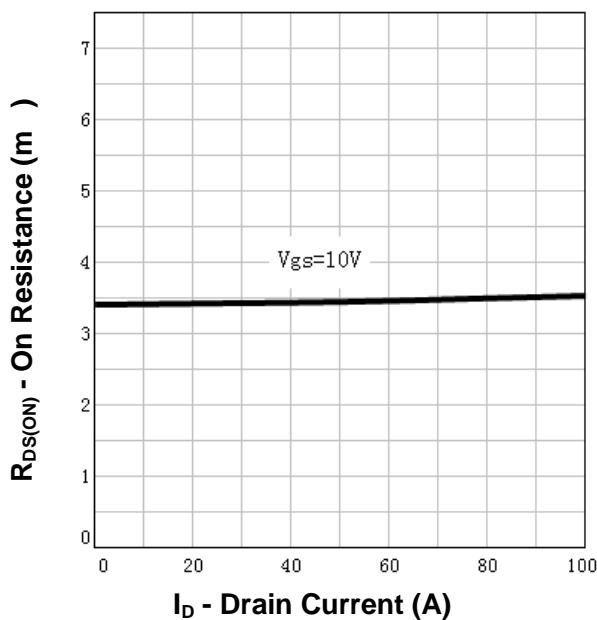


Typical Characteristics

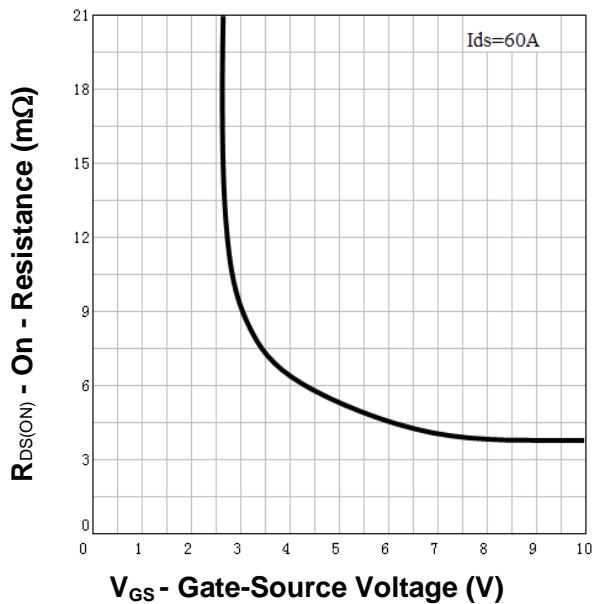
Output Characteristics



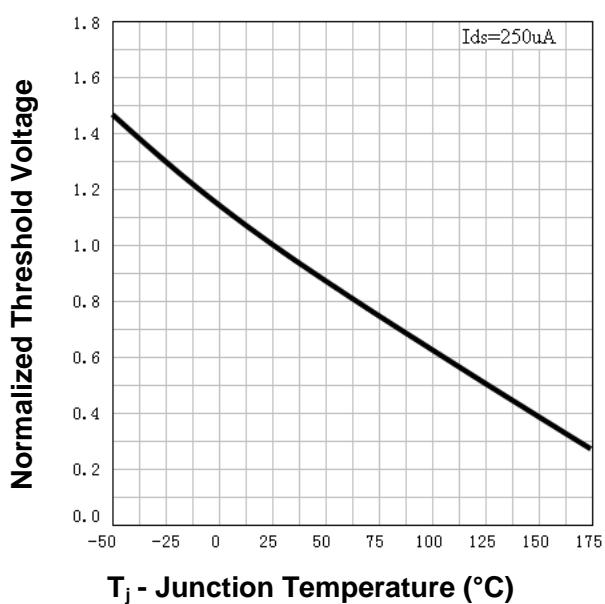
Drain-Source On Resistance



Drain-Source On Resistance

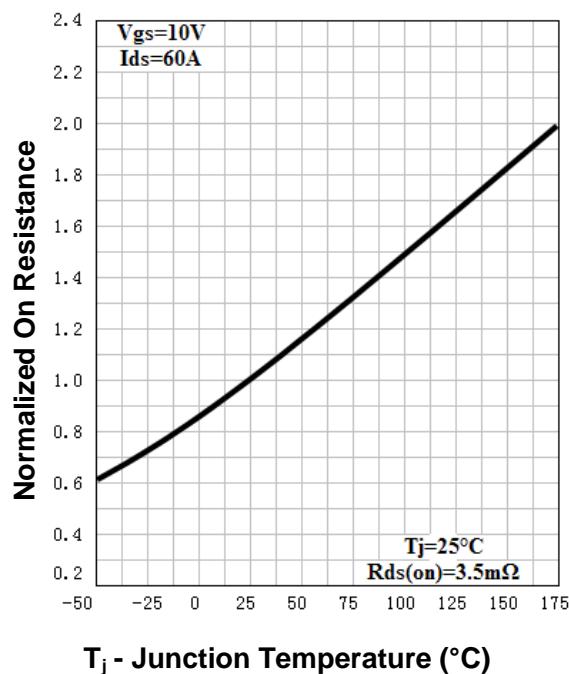


Gate Threshold Voltage

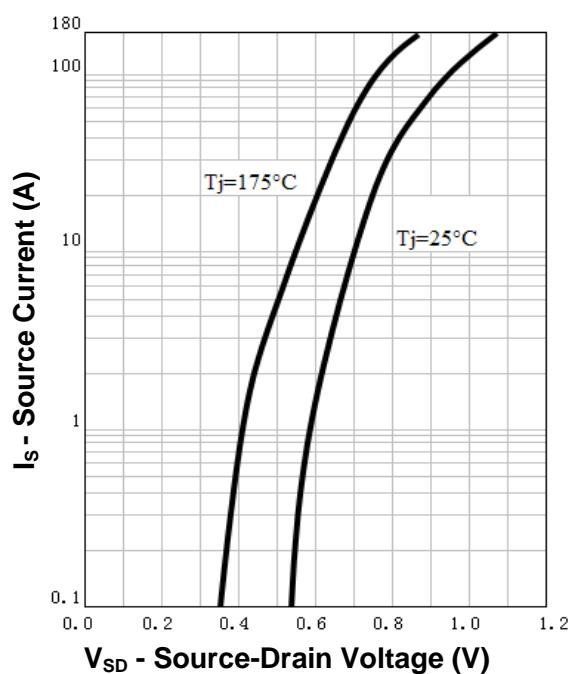


Typical Characteristics

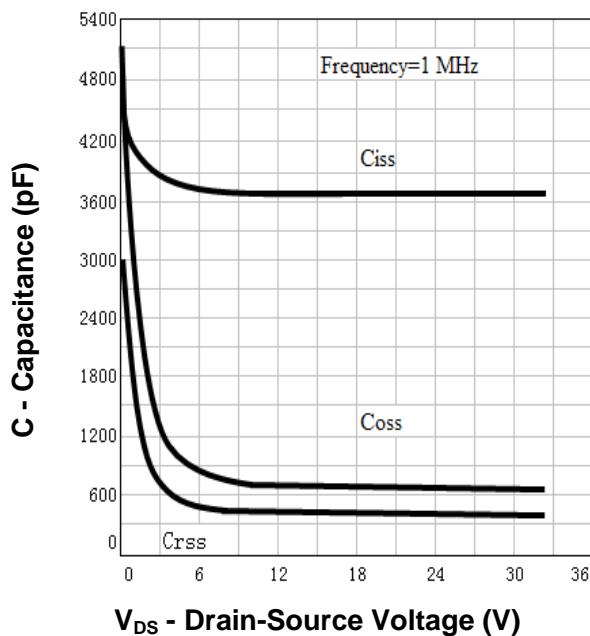
Drain-Source On Resistance



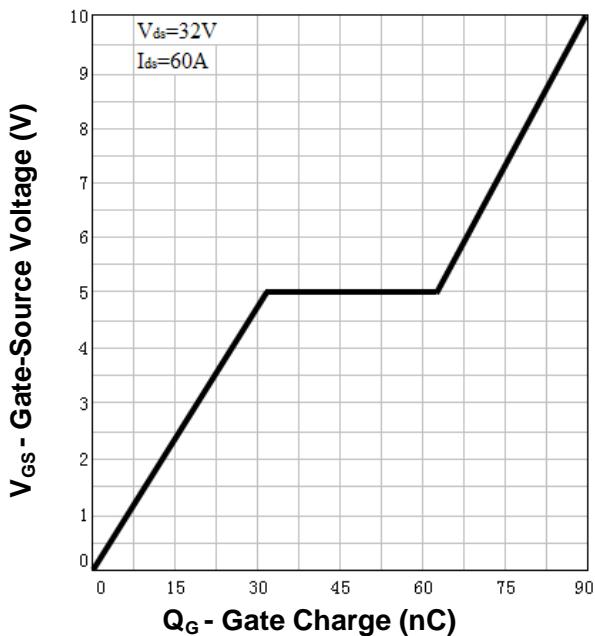
Source-Drain Diode Forward



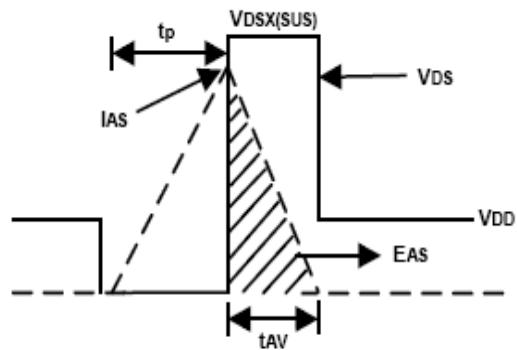
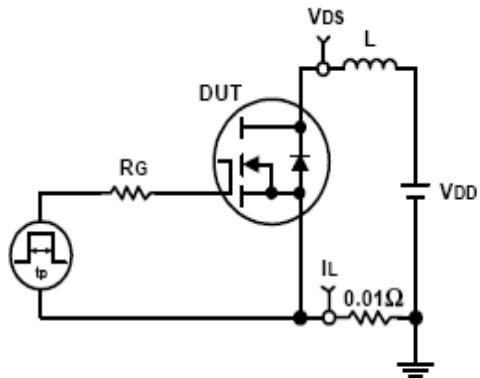
Capacitance



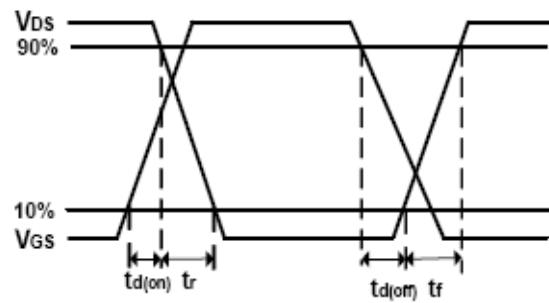
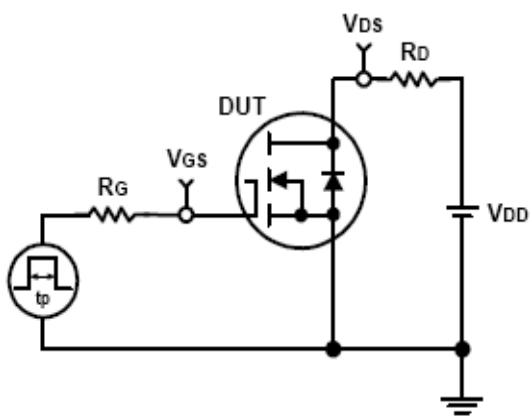
Gate Charge



Avalanche Test Circuit and Waveforms



Switching Time Test Circuit and Waveforms

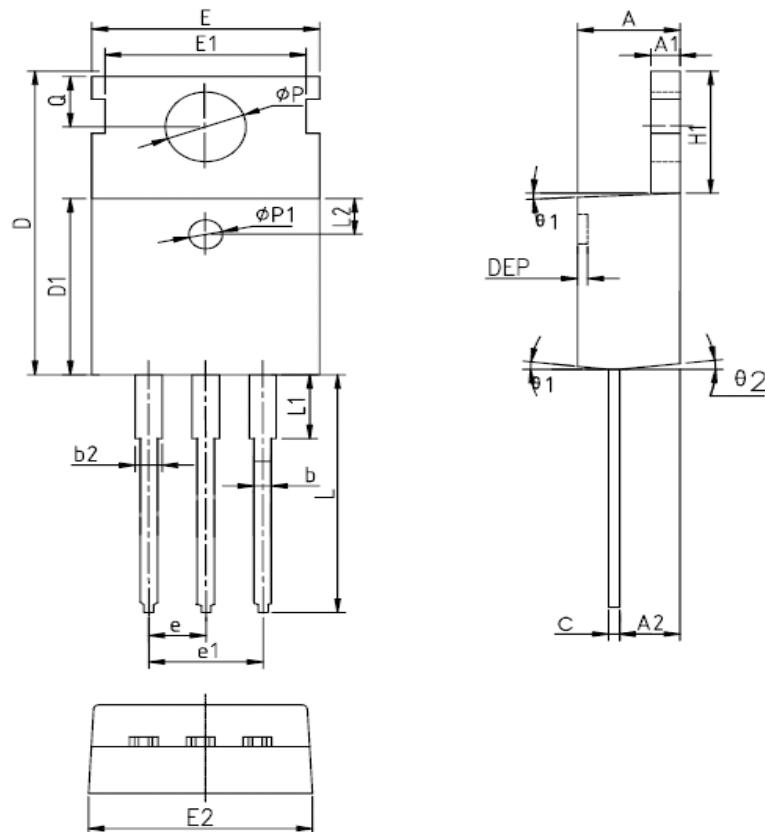


Ordering and Marking Information

Device	Marking	Package	Packaging	Quantity	Reel Size	Tape width
RU40120R	RU40120R	TO-220	Tube	50	-	-

Package Information

TO-220FB-3L



SYMBOL	MM			INCH			SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX		MIN	NOM	MAX	MIN	NOM	MAX
A	4.40	4.57	4.70	0.173	0.180	0.185	θp1	1.40	1.50	1.60	0.055	0.059	0.063
A1	1.27	1.30	1.33	0.050	0.051	0.052	e	2.54BSC			0.1BSC		
A2	2.35	2.40	2.50	0.093	0.094	0.098	e1	5.08BSC			0.2BSC		
b	0.77	-	0.90	0.030	-	0.035	H1	6.40	6.50	6.60	0.252	0.256	0.260
b2	1.23	-	1.36	0.048	-	0.054	L	12.75	-	13.17	0.502	-	0.519
C	0.48	0.50	0.52	0.019	0.020	0.021	L1	-	-	3.95	-	-	0.156
D	15.40	15.60	15.80	0.606	0.614	0.622	L2	2.50REF.			0.098REF.		
D1	9.00	9.10	9.20	0.354	0.358	0.362	θp	3.57	3.60	3.63	0.141	0.142	0.143
DEP	0.05	0.10	0.20	0.002	0.004	0.008	Q	2.73	2.80	2.87	0.107	0.110	0.113
E	9.70	9.90	10.10	0.382	0.389	0.398	θ 1	5°	7°	9°	5°	7°	9°
E1	-	8.70	-	-	0.343	-	θ 2	1°	3°	5°	1°	3°	5°
E2	9.80	10.00	10.20	0.386	0.394	0.401							

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